

# Highly Sensitive H<sub>2</sub>S Detection for SF<sub>6</sub> Decomposition Based on Photoacoustic Spectroscopy

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**Abstract:** A ppb-level hydrogen sulfide (H<sub>2</sub>S) gas sensor for sulfur hexafluoride (SF<sub>6</sub>) decomposition analysis was developed using photoacoustic spectroscopy technique and a watt-level excitation laser source. A minimum detection limit of 109 ppb was achieved. © 2018 The Author(s)  
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## 1. Introduction

Sulfur hexafluoride (SF<sub>6</sub>) gas has an excellent insulating property, which is widely used as an insulating medium in electric power systems, such as in gas-insulated switchgear (GIS), gas circuit breakers (GCBs), transformers (GIT) and transmission pipes (GIL) [1]. Normally, SF<sub>6</sub> is hard to decompose, but with successive reactions with contaminants such as water vapor and oxygen, various chemical byproducts, such as H<sub>2</sub>S, SO<sub>2</sub>, SF<sub>4</sub>, CO, CF<sub>4</sub> and SOF<sub>2</sub> are generated, which can chemically attack solid insulation materials and accelerate insulation aging and eventually lead to power system failure. There is considerable interest in developing a sensitive, selective, and cost-effective sensor for H<sub>2</sub>S detection in a SF<sub>6</sub> buffer gas environment, as it was recognized that the H<sub>2</sub>S and SO<sub>2</sub> concentration levels can effectively determine the insulation condition of the electrical equipment [2, 3].

We report a photoacoustic spectroscopy (PAS) based sensor system for H<sub>2</sub>S detection in SF<sub>6</sub> buffer gas [4]. A near-IR telecommunication diode laser was employed to reduce the cost and its power was boosted up to ~1.4 W by means of a low-cost, erbium-doped optical fiber amplifier (EDFA). A differential photoacoustic cell (PAC) was designed, which has a ~4 times higher quality factor for SF<sub>6</sub> than in N<sub>2</sub>. As a result, a ppb-level SF<sub>6</sub> detection sensitivity was achieved.

## 2. Experimental setup and results

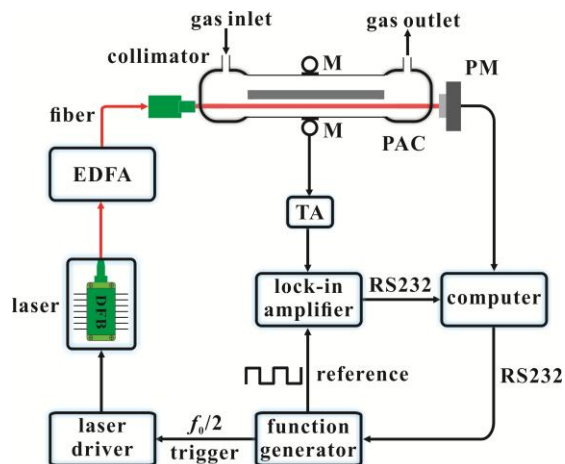


Fig. 1. Schematic of PAS based H<sub>2</sub>S sensor system using a photoacoustic cell and a fiber amplified diode laser. EDFA: erbium-doped fiber amplifier; PAC: photoacoustic cell; PM: power meter; M: microphone and TA: transimpedance amplifier.

A schematic diagram of a PAS based H<sub>2</sub>S sensor system is depicted in Fig. 1. A 20 mW telecommunication distributed feedback (DFB) laser (FITEC, model FRL 15DCWD) was used to reduce the sensor system cost. Its wavelength could be tuned from 1562 nm to 1582 nm. This laser was mounted onto a driver board, which controls both the DFB laser current and temperature. The current was modulated by a function generator (Agilent, model 33500B) at  $f_0/2$ , where  $f_0$  is the resonant frequency of the PAC. The modulated laser beam was directed to an EDFA (Connect laser technology, model MFAS-L-EY-B-MP), which is used to boost the incident laser excitation power. The output laser beam from the EDFA with an output power of 1.36 W was directed to a fiber collimator (OZ optics,

model LPC-01) and then passed through a differential PAC. The PAC had two identical cylindrical resonators, each of which was 6×90 mm in size. Two electret condenser microphones were mounted on the walls in the middle of each resonator to detect the photoacoustic signals. The signals from the two microphones are differentially amplified. As a result, all noise components that are coherent in the two resonators and microphones, such as the flow, window noise and external electromagnetic disturbance are effectively suppressed and thus the signal-to-noise ratio (SNR) of the reported sensor system is increased. The differential signals were amplified by a transimpedance amplifier (TA) and then fed into a lock-in amplifier (Stanford research system, model SR830), which was used to demodulate the signals at  $2f$  harmonics. The lock-in amplifier was set to a 1 s time constant and 12 dB/oct filter slope, corresponding to a detection bandwidth of 0.25 Hz.

A gas dilution system (EnviroNics, model EN4000) was used to generate different concentrations of  $\text{H}_2\text{S}$  in  $\text{N}_2$  or  $\text{SF}_6$  buffer gas, respectively. A sampling system containing a diaphragm pump (KNF technology, model N813.5ANE), a pressure controller (ALICAT, model SL030) and a needle valve was used to control and maintain the sensor system pressure and gas flow. The gas flow rate was set at a constant value of 70 sccm for our experimental analysis.

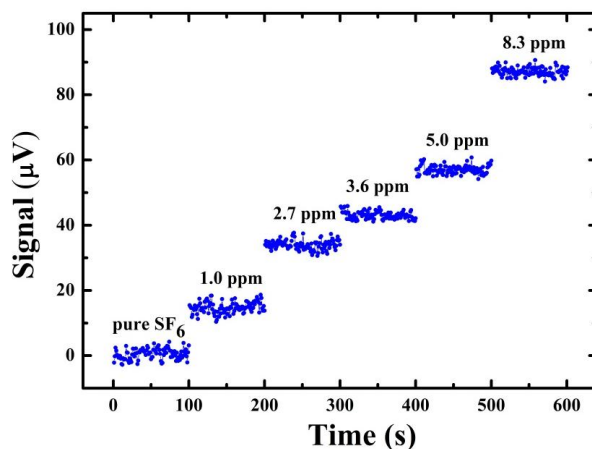


Fig. 2. Time sequence of concentration measurements for pure  $\text{SF}_6$  and five different  $\text{H}_2\text{S}$  concentrations.

The interference-free  $\text{H}_2\text{S}$  absorption line at  $6320.6\text{ cm}^{-1}$  was selected as the target line with a line strength of  $1.056 \times 10^{-22}\text{ cm/molecule}$ . The laser temperature was set to  $31.6\text{ }^\circ\text{C}$ . A  $2f$  wavelength-modulation spectroscopy ( $2f$ -WMS) technology was employed to obtain the  $\text{H}_2\text{S}$  photoacoustic signals ranging from  $6320\text{ cm}^{-1}$  to  $6322\text{ cm}^{-1}$  by scanning the laser current. Figure 2 shows the time sequence of the concentration measurements for pure  $\text{SF}_6$  and five different  $\text{H}_2\text{S}$  concentrations. The signal amplitudes were recorded continuously for 100 seconds with the laser excitation wavelength locked at the center of the target  $\text{H}_2\text{S}$  absorption line. As shown in Fig. 2, a noise level of  $1.6\text{ }\mu\text{V}$  was observed for pure  $\text{SF}_6$ . For a 1 ppm  $\text{H}_2\text{S}/\text{SF}_6$  gas mixture, a mean signal of  $14.7\text{ }\mu\text{V}$  was obtained and the SNR is 9.2. The minimum detection limit ( $1\sigma$ ) for  $\text{H}_2\text{S}$  is 109 ppb for a 1 s averaging time, which corresponds to a normalized noise equivalent absorption (NNEA) coefficient of  $2.9 \times 10^{-9}\text{ cm}^{-1}\text{WHz}^{-1/2}$ .

### 3. Conclusions

A ppb-level PAS  $\text{H}_2\text{S}$  sensor for  $\text{SF}_6$  decomposition analysis was developed and demonstrated. The strength of the selected near-IR absorption line is  $\sim 10$  times weaker than the absorption line in the mid-IR spectral regions, but was compensated by means of an erbium-doped optical fiber amplifier. The differential design of the PAC with a relative larger resonator diameter is capable of suppressing the noise and accommodates the high-power excitation source. These two factors work together and result in a minimum detection limit for  $\text{H}_2\text{S}$  of 109 ppb for a 1 s averaging time.

### 4. References

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